Dual-Channel, Digital Isolators, Enhanced System-Level ESD Reliability

ADuM3200/ADuM3201

FEATURES

Enhanced system-level ESD performance per IEC 61000-4-x
Narrow body, RoHS-compliant, 8-lead SOIC
Low power operation
   5 V operation
      1.6 mA per channel maximum @ 0 Mbps to 2 Mbps
      3.7 mA per channel maximum @ 10 Mbps
      7.5 mA per channel maximum @ 25 Mbps
   3 V operation
      1.4 mA per channel maximum @ 0 Mbps to 2 Mbps
      2.4 mA per channel maximum @ 10 Mbps
      4.6 mA per channel maximum @ 25 Mbps
Bidirectional communication
3 V/5 V level translation
High temperature operation: 105°C
High data rate: dc to 25 Mbps (NRZ)
Precise timing characteristics
   3 ns maximum pulse width distortion
   3 ns maximum channel-to-channel matching
High common-mode transient immunity: >25 kV/μs
Safety and regulatory approvals
   UL recognition: 2500 V rms for 1 minute per UL 1577
   CSA Component Acceptance Notice #5A
   VDE Certificate of Conformity
      DIN V VDE V 0884-10 (VDE V 0884-10): 2006-12
      V_{IORM} = 560 V peak

APPLICATIONS

Size-critical multichannel isolation
SPI interface/data converter isolation
RS-232/RS-422/RS-485 transceiver isolation
Digital field bus isolation

GENERAL DESCRIPTION

The ADuM320x[1] are dual-channel, digital isolators based on the Analog Devices, Inc. *i*Coupler® technology. Combining high speed CMOS and monolithic transformer technology, these isolation components provide outstanding performance characteristics superior to alternatives such as optocoupler devices.

By avoiding the use of LEDs and photodiodes, *i*Coupler devices remove the design difficulties commonly associated with optocouplers. The typical optocoupler concerns regarding uncertain current transfer ratios, nonlinear transfer functions, and temperature and lifetime effects are eliminated with the simple *i*Coupler digital interfaces and stable performance characteristics. The need for external drivers and other discrete components is eliminated with these *i*Coupler products. Furthermore, *i*Coupler devices consume one-tenth to one-sixth the power of optocouplers at comparable signal data rates.

The ADuM320x isolators provide two independent isolation channels in a variety of channel configurations and data rates (see the Ordering Guide). Both parts operate with the supply voltage on either side ranging from 2.7 V to 5.5 V, providing compatibility with lower voltage systems as well as enabling a voltage translation functionality across the isolation barrier. The ADuM320x isolators have a patented refresh feature that ensures dc correctness in the absence of input logic transitions and during power-up/power-down conditions.

In comparison to the ADuM120x isolators, the ADuM320x isolators contain various circuit and layout changes to provide increased capability relative to system-level IEC 61000-4-x testing (ESD, burst, and surge). The precise capability in these tests for either the ADuM120x or ADuM320x products is strongly determined by the design and layout of the user's board or module. For more information, see Application Note AN-793, ESD/Latch-Up Considerations with *i*Coupler Isolation Products.

[1] Protected by U.S. Patents 5,952,849; 6,873,065; 7,075,329 and other pending patents.
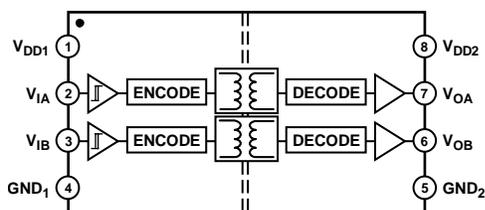
FUNCTIONAL BLOCK DIAGRAMS
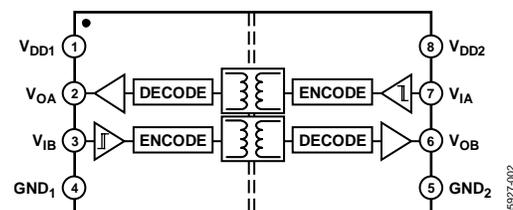

Figure 1. ADuM3200 Functional Block Diagram

Figure 2. ADuM3201 Functional Block Diagram

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REVISION HISTORY

6/07—Rev. 0 to Rev. A

7/06—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS—5 V OPERATION

All voltages are relative to their respective ground. $4.5\ V \le V_{DD1} \le 5.5\ V$, $4.5\ V \le V_{DD2} \le 5.5\ V$. All minimum/maximum specifications apply over the entire recommended operating range, unless otherwise noted. All typical specifications are at $T_A = 25°C$, $V_{DD1} = V_{DD2} = 5\ V$.

Table 1.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
DC SPECIFICATIONS						
Input Supply Current, per Channel, Quiescent	$I_{DDI\ (Q)}$		0.4	0.8	mA	
Output Supply Current, per Channel, Quiescent	$I_{DDO\ (Q)}$		0.5	0.6	mA	
ADuM3200, Total Supply Current, Two Channels[1]						
DC to 2 Mbps						
V_{DD1} Supply Current	$I_{DD1\ (Q)}$		1.3	1.7	mA	DC to 1 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\ (Q)}$		1.0	1.6	mA	DC to 1 MHz logic signal freq.
10 Mbps (BR and CR Grades Only)						
V_{DD1} Supply Current	$I_{DD1\ (10)}$		3.5	4.6	mA	5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\ (10)}$		1.7	2.8	mA	5 MHz logic signal freq.
25 Mbps (CR Grade Only)						
V_{DD1} Supply Current	$I_{DD1\ (25)}$		7.7	10.0	mA	12.5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\ (25)}$		3.1	3.9	mA	12.5 MHz logic signal freq.
ADuM3201, Total Supply Current, Two Channels[1]						
DC to 2 Mbps						
V_{DD1} Supply Current	$I_{DD1\ (Q)}$		1.1	1.5	mA	DC to 1 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\ (Q)}$		1.3	1.8	mA	DC to 1 MHz logic signal freq.
10 Mbps (BR and CR Grades Only)						
V_{DD1} Supply Current	$I_{DD1\ (10)}$		2.6	3.4	mA	5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\ (10)}$		3.1	4.0	mA	5 MHz logic signal freq.
25 Mbps (CR Grade Only)						
V_{DD1} Supply Current	$I_{DD1\ (25)}$		5.3	6.8	mA	12.5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\ (25)}$		6.4	8.3	mA	12.5 MHz logic signal freq.
For All Models						
Input Currents	I_{IA}, I_{IB}	−10	+0.01	+10	μA	$0\ V \le V_{IA}$, $V_{IB} \le V_{DD1}$ or V_{DD2}
Logic High Input Threshold	V_{IH}	0.7 (V_{DD1} or V_{DD2})			V	
Logic Low Input Threshold	V_{IL}			0.3 (V_{DD1} or V_{DD2})	V	
Logic High Output Voltages	V_{OAH}	(V_{DD1} or V_{DD2}) − 0.1	5.0		V	$I_{Ox} = −20\ μA$, $V_{Ix} = V_{IxH}$
	V_{OBH}	(V_{DD1} or V_{DD2}) − 0.5	4.8		V	$I_{Ox} = −4\ mA$, $V_{Ix} = V_{IxH}$
Logic Low Output Voltages	V_{OAL}		0.0	0.1	V	$I_{Ox} = 20\ μA$, $V_{Ix} = V_{IxL}$
	V_{OBL}		0.04	0.1	V	$I_{Ox} = 400\ μA$, $V_{Ix} = V_{IxL}$
			0.2	0.4	V	$I_{Ox} = 4\ mA$, $V_{Ix} = V_{IxL}$
SWITCHING SPECIFICATIONS						
ADuM320xAR						
Minimum Pulse Width[2]	PW			1000	ns	$C_L = 15\ pF$, CMOS signal levels
Maximum Data Rate[3]		1			Mbps	$C_L = 15\ pF$, CMOS signal levels
Propagation Delay[4]	t_{PHL}, t_{PLH}	20		150	ns	$C_L = 15\ pF$, CMOS signal levels
Pulse Width Distortion, $|t_{PLH} − t_{PHL}|$[4]	PWD			40	ns	$C_L = 15\ pF$, CMOS signal levels
Propagation Delay Skew[5]	t_{PSK}			100	ns	$C_L = 15\ pF$, CMOS signal levels
Channel-to-Channel Matching[6]	$t_{PSKCD/OD}$			50	ns	$C_L = 15\ pF$, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F		10		ns	$C_L = 15\ pF$, CMOS signal levels

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
ADuM320xBR						
Minimum Pulse Width[2]	PW			100	ns	C_L = 15 pF, CMOS signal levels
Maximum Data Rate[3]		10			Mbps	C_L = 15 pF, CMOS signal levels
Propagation Delay[4]	t_{PHL}, t_{PLH}	20		50	ns	C_L = 15 pF, CMOS signal levels
Pulse Width Distortion, $\lvert t_{PLH} - t_{PHL} \rvert$[4]	PWD			3	ns	C_L = 15 pF, CMOS signal levels
Change vs. Temperature			5		ps/°C	C_L = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t_{PSK}			15	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Codirectional Channels[6]	t_{PSKCD}			3	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Opposing Directional Channels[6]	t_{PSKOD}			15	ns	C_L = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F		2.5		ns	C_L = 15 pF, CMOS signal levels
ADuM320xCR						
Minimum Pulse Width[2]	PW		20	40	ns	C_L = 15 pF, CMOS signal levels
Maximum Data Rate[3]		25	50		Mbps	C_L = 15 pF, CMOS signal levels
Propagation Delay[4]	t_{PHL}, t_{PLH}	20		45	ns	C_L = 15 pF, CMOS signal levels
Pulse Width Distortion, $\lvert t_{PLH} - t_{PHL} \rvert$[4]	PWD			3	ns	C_L = 15 pF, CMOS signal levels
Change vs. Temperature			5		ps/°C	C_L = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t_{PSK}			15	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Codirectional Channels[6]	t_{PSKCD}			3	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Opposing Directional Channels[6]	t_{PSKOD}			15	ns	C_L = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F		2.5		ns	C_L = 15 pF, CMOS signal levels
For All Models						
Common-Mode Transient Immunity at Logic High Output[7]	$\lvert CM_H \rvert$	25	35		kV/µs	V_{Ix} = V_{DD1} or V_{DD2}, V_{CM} = 1000 V, transient magnitude = 800 V
Common-Mode Transient Immunity at Logic Low Output[7]	$\lvert CM_L \rvert$	25	35		kV/µs	V_{Ix} = 0 V, V_{CM} = 1000 V, transient magnitude = 800 V
Refresh Rate	f_r		1.2		Mbps	
Input Dynamic Supply Current, per Channel[8]	$I_{DDI (D)}$		0.19		mA/Mbps	
Output Dynamic Supply Current, per Channel[8]	$I_{DDO (D)}$		0.05		mA/Mbps	

[1] The supply current values for both channels are combined when running at identical data rates. Output supply current values are specified with no output load present. The supply current associated with an individual channel operating at a given data rate can be calculated as described in the Power Consumption section. See Figure 6 through Figure 8 for information on per-channel supply current as a function of data rate for unloaded and loaded conditions. See Figure 9 through Figure 11 for total I_{DD1} and I_{DD2} supply currents as a function of data rate for ADuM3200 and ADuM3201 channel configurations.

[2] The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.

[3] The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.

[4] t_{PHL} propagation delay is measured from the 50% level of the falling edge of the V_{Ix} signal to the 50% level of the falling edge of the V_{Ox} signal. t_{PLH} propagation delay is measured from the 50% level of the rising edge of the V_{Ix} signal to the 50% level of the rising edge of the V_{Ox} signal.

[5] t_{PSK} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.

[6] Codirectional channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier. Opposing directional channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on opposing sides of the isolation barrier.

[7] CM_H is the maximum common-mode voltage slew rate that can be sustained while maintaining V_O > 0.8 V_{DD2}. CM_L is the maximum common-mode voltage slew rate that can be sustained while maintaining V_O < 0.8 V. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges. The transient magnitude is the range over which the common mode is slewed.

[8] Dynamic supply current is the incremental amount of supply current required for a 1 Mbps increase in the signal data rate. See Figure 6 through Figure 8 for information on per-channel supply current for unloaded and loaded conditions. See the Power Consumption section for guidance on calculating per-channel supply current for a given data rate.

ELECTRICAL CHARACTERISTICS—3 V OPERATION

All voltages are relative to their respective ground. $2.7\ V \le V_{DD1} \le 3.6\ V$, $2.7\ V \le V_{DD2} \le 3.6\ V$. All minimum/maximum specifications apply over the entire recommended operating range, unless otherwise noted. All typical specifications are at $T_A = 25°C$, $V_{DD1} = V_{DD2} = 3.0\ V$.

Table 2.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
DC SPECIFICATIONS						
Input Supply Current, per Channel, Quiescent	$I_{DDI\,(Q)}$		0.3	0.5	mA	
Output Supply Current, per Channel, Quiescent	$I_{DDO\,(Q)}$		0.3	0.5	mA	
ADuM3200, Total Supply Current, Two Channels[1]						
DC to 2 Mbps						
V_{DD1} Supply Current	$I_{DD1\,(Q)}$		0.8	1.3	mA	DC to 1 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(Q)}$		0.7	1.0	mA	DC to 1 MHz logic signal freq.
10 Mbps (BR and CR Grades Only)						
V_{DD1} Supply Current	$I_{DD1\,(10)}$		2.0	3.2	mA	5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(10)}$		1.1	1.7	mA	5 MHz logic signal freq.
25 Mbps (CR Grade Only)						
V_{DD1} Supply Current	$I_{DD1\,(25)}$		4.3	6.4	mA	12.5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(25)}$		1.8	2.4	mA	12.5 MHz logic signal freq.
ADuM3201, Total Supply Current, Two Channels[1]						
DC to 2 Mbps						
V_{DD1} Supply Current	$I_{DD1\,(Q)}$		0.7	1.3	mA	DC to 1 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(Q)}$		0.8	1.6	mA	DC to 1 MHz logic signal freq.
10 Mbps (BR and CR Grades Only)						
V_{DD1} Supply Current	$I_{DD1\,(10)}$		1.5	2.1	mA	5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(10)}$		1.9	2.4	mA	5 MHz logic signal freq.
25 Mbps (CR Grade Only)						
V_{DD1} Supply Current	$I_{DD1\,(25)}$		3.0	4.2	mA	12.5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(25)}$		3.6	5.1	mA	12.5 MHz logic signal freq.
For All Models						
Input Currents	I_{IA}, I_{IB}	−10	+0.01	+10	µA	$0\ V \le V_{IA}, V_{IB}, \le V_{DD1}$ or V_{DD2}
Logic High Input Threshold	V_{IH}	0.7 (V_{DD1} or V_{DD2})			V	
Logic Low Input Threshold	V_{IL}			0.3 (V_{DD1} or V_{DD2})	V	
Logic High Output Voltages	V_{OAH}	(V_{DD1} or V_{DD2}) − 0.1	3.0		V	$I_{Ox} = −20\ µA$, $V_{Ix} = V_{IxH}$
	V_{OBH}	(V_{DD1} or V_{DD2}) − 0.5	2.8		V	$I_{Ox} = −4\ mA$, $V_{Ix} = V_{IxH}$
Logic Low Output Voltages	V_{OAL}		0.0	0.1	V	$I_{Ox} = 20\ µA$, $V_{Ix} = V_{IxL}$
	V_{OBL}		0.04	0.1	V	$I_{Ox} = 400\ µA$, $V_{Ix} = V_{IxL}$
			0.2	0.4	V	$I_{Ox} = 4\ mA$, $V_{Ix} = V_{IxL}$
SWITCHING SPECIFICATIONS						
ADuM320xAR						
Minimum Pulse Width[2]	PW			1000	ns	$C_L = 15\ pF$, CMOS signal levels
Maximum Data Rate[3]		1			Mbps	$C_L = 15\ pF$, CMOS signal levels
Propagation Delay[4]	t_{PHL}, t_{PLH}	20		150	ns	$C_L = 15\ pF$, CMOS signal levels
Pulse Width Distortion, $|t_{PLH} − t_{PHL}|$[4]	PWD			40	ns	$C_L = 15\ pF$, CMOS signal levels
Propagation Delay Skew[5]	t_{PSK}			100	ns	$C_L = 15\ pF$, CMOS signal levels
Channel-to-Channel Matching[6]	$t_{PSKCD/OD}$			50	ns	$C_L = 15\ pF$, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F		10		ns	$C_L = 15\ pF$, CMOS signal levels

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
ADuM320xBR						
Minimum Pulse Width[2]	PW			100	ns	C_L = 15 pF, CMOS signal levels
Maximum Data Rate[3]		10			Mbps	C_L = 15 pF, CMOS signal levels
Propagation Delay[4]	t_{PHL}, t_{PLH}	20		60	ns	C_L = 15 pF, CMOS signal levels
Pulse Width Distortion, $|t_{PLH} - t_{PHL}|$[4]	PWD			3	ns	C_L = 15 pF, CMOS signal levels
Change vs. Temperature			5		ps/°C	C_L = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t_{PSK}			22	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Codirectional Channels[6]	t_{PSKCD}			3	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Opposing Directional Channels[6]	t_{PSKOD}			22	ns	C_L = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F		3.0		ns	C_L = 15 pF, CMOS signal levels
ADuM320xCR						
Minimum Pulse Width[2]	PW		20	40	ns	C_L = 15 pF, CMOS signal levels
Maximum Data Rate[3]		25	50		Mbps	C_L = 15 pF, CMOS signal levels
Propagation Delay[4]	t_{PHL}, t_{PLH}	20		55	ns	C_L = 15 pF, CMOS signal levels
Pulse Width Distortion, $|t_{PLH} - t_{PHL}|$[4]	PWD			3	ns	C_L = 15 pF, CMOS signal levels
Change vs. Temperature			5		ps/°C	C_L = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t_{PSK}			16	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Codirectional Channels[6]	t_{PSKCD}			3	ns	C_L = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Opposing Directional Channels[6]	t_{PSKOD}			16	ns	C_L = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F		3.0		ns	C_L = 15 pF, CMOS signal levels
For All Models						
Common-Mode Transient Immunity at Logic High Output[7]	$|CM_H|$	25	35		kV/μs	V_{Ix} = V_{DD1} or V_{DD2}, V_{CM} = 1000 V, transient magnitude = 800 V
Common-Mode Transient Immunity at Logic Low Output[7]	$|CM_L|$	25	35		kV/μs	V_{Ix} = 0 V, V_{CM} = 1000 V, transient magnitude = 800 V
Refresh Rate	f_r		1.1		Mbps	
Input Dynamic Supply Current, per Channel[8]	$I_{DDI (D)}$		0.10		mA/Mbps	
Output Dynamic Supply Current, per Channel[8]	$I_{DDO (D)}$		0.03		mA/Mbps	

[1] The supply current values for both channels are combined when running at identical data rates. Output supply current values are specified with no output load present. The supply current associated with an individual channel operating at a given data rate may be calculated as described in the Power Consumption section. See Figure 6 through Figure 8 for information on per-channel supply current as a function of data rate for unloaded and loaded conditions. See Figure 9 through Figure 11 for total V_{DD1} and V_{DD2} supply currents as a function of data rate for ADuM3200 and ADuM3201 channel configurations.

[2] The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.

[3] The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.

[4] t_{PHL} propagation delay is measured from the 50% level of the falling edge of the V_{Ix} signal to the 50% level of the falling edge of the V_{Ox} signal. t_{PLH} propagation delay is measured from the 50% level of the rising edge of the V_{Ix} signal to the 50% level of the rising edge of the V_{Ox} signal.

[5] t_{PSK} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.

[6] Codirectional channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier. Opposing directional channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on opposing sides of the isolation barrier.

[7] CM_H is the maximum common-mode voltage slew rate that can be sustained while maintaining V_O > 0.8 V_{DD2}. CM_L is the maximum common-mode voltage slew rate that can be sustained while maintaining V_O < 0.8 V. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges. The transient magnitude is the range over which the common mode is slewed.

[8] Dynamic supply current is the incremental amount of supply current required for a 1 Mbps increase in the signal data rate. See Figure 6 through Figure 8 for information on per-channel supply current for unloaded and loaded conditions. See the Power Consumption section for guidance on calculating per-channel supply current for a given data rate.

ELECTRICAL CHARACTERISTICS—MIXED 5 V/3 V OR 3 V/5 V OPERATION

All voltages are relative to their respective ground. 5 V/3 V operation: $4.5\ V \leq V_{DD1} \leq 5.5\ V$, $2.7\ V \leq V_{DD2} \leq 3.6\ V$. 3 V/5 V operation: $2.7\ V \leq V_{DD1} \leq 3.6\ V$, $4.5\ V \leq V_{DD2} \leq 5.5\ V$. All minimum/maximum specifications apply over the entire recommended operating range, unless otherwise noted. All typical specifications are at $T_A = 25°C$; $V_{DD1} = 3.0\ V$, $V_{DD2} = 5.0\ V$; or $V_{DD1} = 5.0\ V$, $V_{DD2} = 3.0\ V$.

Table 3.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
DC SPECIFICATIONS						
Input Supply Current, per Channel, Quiescent	$I_{DDI\,(Q)}$					
5 V/3 V Operation			0.4	0.8	mA	
3 V/5 V Operation			0.3	0.5	mA	
Output Supply Current, per Channel, Quiescent	$I_{DDO\,(Q)}$					
5 V/3 V Operation			0.3	0.5	mA	
3 V/5 V Operation			0.5	0.6	mA	
ADuM3200, Total Supply Current, Two Channels[1]						
DC to 2 Mbps						
V_{DD1} Supply Current	$I_{DD1\,(Q)}$					
5 V/3 V Operation			1.3	1.7	mA	DC to 1 MHz logic signal freq.
3 V/5 V Operation			0.8	1.3	mA	DC to 1 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(Q)}$					
5 V/3 V Operation			0.7	1.0	mA	DC to 1 MHz logic signal freq.
3 V/5 V Operation			1.0	1.6	mA	DC to 1 MHz logic signal freq.
10 Mbps (BR and CR Grades Only)						
V_{DD1} Supply Current	$I_{DD1\,(10)}$					
5 V/3 V Operation			3.5	4.6	mA	5 MHz logic signal freq.
3 V/5 V Operation			2.0	3.2	mA	5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(10)}$					
5 V/3 V Operation			1.1	1.7	mA	5 MHz logic signal freq.
3 V/5 V Operation			1.7	2.8	mA	5 MHz logic signal freq.
25 Mbps (CR Grade Only)						
V_{DD1} Supply Current	$I_{DD1\,(25)}$					
5 V/3 V Operation			7.7	10.0	mA	12.5 MHz logic signal freq.
3 V/5 V Operation			4.3	6.4	mA	12.5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(25)}$					
5 V/3 V Operation			1.8	2.4	mA	12.5 MHz logic signal freq.
3 V/5 V Operation			3.1	3.9	mA	12.5 MHz logic signal freq.
ADuM3201, Total Supply Current, Two Channels[1]						
DC to 2 Mbps						
V_{DD1} Supply Current	$I_{DD1\,(Q)}$					
5 V/3 V Operation			1.1	1.5	mA	DC to 1 MHz logic signal freq.
3 V/5 V Operation			0.7	1.3	mA	DC to 1 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(Q)}$					
5 V/3 V Operation			0.8	1.6	mA	DC to 1 MHz logic signal freq.
3 V/5 V Operation			1.3	1.8	mA	DC to 1 MHz logic signal freq.
10 Mbps (BR and CR Grades Only)						
V_{DD1} Supply Current	$I_{DD1\,(10)}$					
5 V/3 V Operation			2.6	3.4	mA	5 MHz logic signal freq.
3 V/5 V Operation			1.5	2.1	mA	5 MHz logic signal freq.
V_{DD2} Supply Current	$I_{DD2\,(10)}$					
5 V/3 V Operation			1.9	2.4	mA	5 MHz logic signal freq.
3 V/5 V Operation			3.1	4.0	mA	5 MHz logic signal freq.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
25 Mbps (CR Grade Only)						
V$_{DD1}$ Supply Current	I$_{DD1 (25)}$					
5 V/3 V Operation			5.3	6.8	mA	12.5 MHz logic signal freq.
3 V/5 V Operation			3.0	4.2	mA	12.5 MHz logic signal freq.
V$_{DD2}$ Supply Current	I$_{DD2 (25)}$					
5 V/3 V Operation			3.6	5.1	mA	12.5 MHz logic signal freq.
3 V/5 V Operation			6.4	8.3	mA	12.5 MHz logic signal freq.
For All Models						
Input Currents	I$_{IA}$, I$_{IB}$	−10	+0.01	+10	µA	0 V ≤ V$_{IA}$, V$_{IB}$ ≤ V$_{DD1}$ or V$_{DD2}$
Logic High Input Threshold	V$_{IH}$	0.7 (V$_{DD1}$ or V$_{DD2}$)			V	
Logic Low Input Threshold	V$_{IL}$			0.3 (V$_{DD1}$ or V$_{DD2}$)	V	
Logic High Output Voltages	V$_{OAH}$, V$_{OBH}$	(V$_{DD1}$ or V$_{DD2}$) − 0.1	(V$_{DD1}$ or V$_{DD2}$)		V	I$_{Ox}$ = −20 µA, V$_{Ix}$ = V$_{IxH}$
		(V$_{DD1}$ or V$_{DD2}$) − 0.5	(V$_{DD1}$ or V$_{DD2}$) − 0.2		V	I$_{Ox}$ = −4 mA, V$_{Ix}$ = V$_{IxH}$
Logic Low Output Voltages	V$_{OAL}$, V$_{OBL}$		0.0	0.1	V	I$_{Ox}$ = 20 µA, V$_{Ix}$ = V$_{IxL}$
			0.04	0.1	V	I$_{Ox}$ = 400 µA, V$_{Ix}$ = V$_{IxL}$
			0.2	0.4	V	I$_{Ox}$ = 4 mA, V$_{Ix}$ = V$_{IxL}$
SWITCHING SPECIFICATIONS						
ADuM320xAR						
Minimum Pulse Width[2]	PW			1000	ns	C$_L$ = 15 pF, CMOS signal levels
Maximum Data Rate[3]		1			Mbps	C$_L$ = 15 pF, CMOS signal levels
Propagation Delay[4]	t$_{PHL}$, t$_{PLH}$	15		150	ns	C$_L$ = 15 pF, CMOS signal levels
Pulse Width Distortion, |t$_{PLH}$ − t$_{PHL}$|[4]	PWD			40	ns	C$_L$ = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t$_{PSK}$			50	ns	C$_L$ = 15 pF, CMOS signal levels
Channel-to-Channel Matching[6]	t$_{PSKCD/OD}$			50	ns	C$_L$ = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t$_R$/t$_F$		10		ns	C$_L$ = 15 pF, CMOS signal levels
ADuM320xBR						
Minimum Pulse Width[2]	PW			100	ns	C$_L$ = 15 pF, CMOS signal levels
Maximum Data Rate[3]		10			Mbps	C$_L$ = 15 pF, CMOS signal levels
Propagation Delay[4]	t$_{PHL}$, t$_{PLH}$	15		55	ns	C$_L$ = 15 pF, CMOS signal levels
Pulse Width Distortion, |t$_{PLH}$ − t$_{PHL}$|[4]	PWD			3	ns	C$_L$ = 15 pF, CMOS signal levels
Change vs. Temperature			5		ps/°C	C$_L$ = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t$_{PSK}$			22	ns	C$_L$ = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Codirectional Channels[6]	t$_{PSKCD}$			3	ns	C$_L$ = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Opposing Directional Channels[6]	t$_{PSKOD}$			22	ns	C$_L$ = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t$_R$/t$_F$					
5 V/3 V Operation			3.0		ns	C$_L$ = 15 pF, CMOS signal levels
3 V/5 V Operation			2.5		ns	C$_L$ = 15 pF, CMOS signal levels
ADuM320xCR						
Minimum Pulse Width[2]	PW		20	40	ns	C$_L$ = 15 pF, CMOS signal levels
Maximum Data Rate[3]		25	50		Mbps	C$_L$ = 15 pF, CMOS signal levels
Propagation Delay[4]	t$_{PHL}$, t$_{PLH}$	20		50	ns	C$_L$ = 15 pF, CMOS signal levels
Pulse Width Distortion, |t$_{PLH}$ − t$_{PHL}$|[4]	PWD			3	ns	C$_L$ = 15 pF, CMOS signal levels
Change vs. Temperature			5		ps/°C	C$_L$ = 15 pF, CMOS signal levels
Propagation Delay Skew[5]	t$_{PSK}$			15	ns	C$_L$ = 15 pF, CMOS signal levels
Channel-to-Channel Matching, Codirectional Channels[6]	t$_{PSKCD}$			3	ns	C$_L$ = 15 pF, CMOS signal levels

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Channel-to-Channel Matching, Opposing Directional Channels[6]	t_{PSKOD}			15	ns	C_L = 15 pF, CMOS signal levels
Output Rise/Fall Time (10% to 90%)	t_R/t_F					
5 V/3 V Operation			3.0		ns	C_L = 15 pF, CMOS signal levels
3 V/5 V Operation			2.5		ns	C_L = 15 pF, CMOS signal levels
For All Models						
Common-Mode Transient Immunity at Logic High Output[7]	$|CM_H|$	25	35		kV/µs	V_{Ix} = V_{DD1} or V_{DD2}, V_{CM} = 1000 V, transient magnitude = 800 V
Common-Mode Transient Immunity at Logic Low Output[7]	$|CM_L|$	25	35		kV/µs	V_{Ix} = 0 V, V_{CM} = 1000 V, transient magnitude = 800 V
Refresh Rate	f_r					
5 V/3 V Operation			1.2		Mbps	
3 V/5 V Operation			1.1		Mbps	
Input Dynamic Supply Current, per Channel[8]	$I_{DDI (D)}$					
5 V/3 V Operation			0.19		mA/Mbps	
3 V/5 V Operation			0.10		mA/Mbps	
Output Dynamic Supply Current, per Channel[8]	$I_{DDO (D)}$					
5 V/3 V Operation			0.03		mA/Mbps	
3 V/5 V Operation			0.05		mA/Mbps	

[1] The supply current values for both channels are combined when running at identical data rates. Output supply current values are specified with no output load present. The supply current associated with an individual channel operating at a given data rate may be calculated as described in the Power Consumption section. See Figure 6 through Figure 8 for information on per-channel supply current as a function of data rate for unloaded and loaded conditions. See Figure 9 through Figure 11 for total V_{DD1} and V_{DD2} supply currents as a function of data rate for ADuM3200 and ADuM3201 channel configurations.

[2] The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.

[3] The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.

[4] t_{PHL} propagation delay is measured from the 50% level of the falling edge of the V_{Ix} signal to the 50% level of the falling edge of the V_{Ox} signal. t_{PLH} propagation delay is measured from the 50% level of the rising edge of the V_{Ix} signal to the 50% level of the rising edge of the V_{Ox} signal.

[5] t_{PSK} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.

[6] Codirectional channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier. Opposing directional channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on opposing sides of the isolation barrier.

[7] CM_H is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD2}$. CM_L is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O < 0.8$ V. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges. The transient magnitude is the range over which the common mode is slewed.

[8] Dynamic supply current is the incremental amount of supply current required for a 1 Mbps increase in the signal data rate. See Figure 6 through Figure 8 for information on per-channel supply current for unloaded and loaded conditions. See the Power Consumption section for guidance on calculating per-channel supply current for a given data rate.

PACKAGE CHARACTERISTICS

Table 4.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Resistance (Input to Output)[1]	R_{I-O}		10^{12}		Ω	
Capacitance (Input to Output)[1]	C_{I-O}		1.0		pF	f = 1 MHz
Input Capacitance	C_I		4.0		pF	
IC Junction-to-Case Thermal Resistance, Side 1	θ_{JCI}		46		°C/W	Thermocouple located at center of package underside
IC Junction-to-Case Thermal Resistance, Side 2	θ_{JCO}		41		°C/W	

[1] The device is considered a 2-terminal device; Pin 1, Pin 2, Pin 3, and Pin 4 are shorted together, and Pin 5, Pin 6, Pin 7, and Pin 8 are shorted together.

REGULATORY INFORMATION

The ADuM3200/ADuM3201 devices are approved by the organizations listed in Table 5. Refer to Table 10 and the Insulation Lifetime section for details regarding recommended maximum working voltages for specific cross-isolation waveforms and insulation levels.

Table 5.

UL	CSA	VDE
Recognized under UL 1577 Component Recognition Program[1]	Approved under CSA Component Acceptance Notice #5A	Certified according to DIN V VDE V 0884-10 (VDE V 0884-10): 2006-12[2]
Single/basic 2500 V rms isolation voltage	Basic insulation per CSA 60950-1-03 and IEC 60950-1, 400 V rms (566 V peak) maximum working voltage	Reinforced insulation, 560 V peak
	Functional insulation per CSA 60950-1-03 and IEC 60950-1, 800 V rms (1131 V peak) maximum working voltage	
File E214100	File 205078	File 2471900-4880-0001

[1] In accordance with UL 1577, each ADuM320x is proof-tested by applying an insulation test voltage ≥3000 V rms for 1 second (current leakage detection limit = 5 µA).
[2] In accordance with DIN V VDE V 0884-10, each ADuM320x is proof tested by applying an insulation test voltage ≥1050 V_{PEAK} for 1 second (partial discharge detection limit = 5 pC). An asterisk (*) marking branded on the component designates DIN V VDE V 0884-10 approval.

INSULATION AND SAFETY-RELATED SPECIFICATIONS

Table 6.

Parameter	Symbol	Value	Unit	Conditions
Rated Dielectric Insulation Voltage		2500	V rms	1-minute duration
Minimum External Air Gap (Clearance)	L(I01)	4.90 min	mm	Measured from input terminals to output terminals, shortest distance through air
Minimum External Tracking (Creepage)	L(I02)	4.01 min	mm	Measured from input terminals to output terminals, shortest distance path along body
Minimum Internal Gap (Internal Clearance)		0.017 min	mm	Insulation distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>175	V	DIN IEC 112/VDE 0303 Part 1
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

DIN V VDE V 0884-10 (VDE V 0884-10) INSULATION CHARACTERISTICS

These isolators are suitable for reinforced isolation only within the safety limit data. Maintenance of the safety data is ensured by protective circuits. The asterisk (*) marking on the package denotes DIN V VDE V 0884-10 approval for a 560 V peak working voltage.

Table 7.

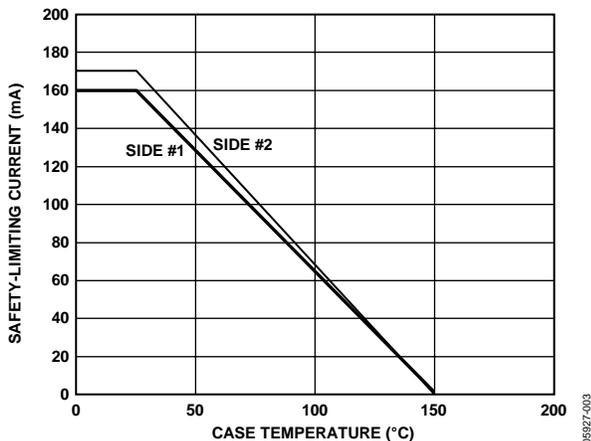| Description	Conditions	Symbol	Characteristic	Unit
Installation Classification per DIN VDE 0110				
For Rated Mains Voltage ≤ 150 V rms			I to IV	
For Rated Mains Voltage ≤ 300 V rms			I to III	
For Rated Mains Voltage ≤ 400 V rms			I to II	
Climatic Classification			40/105/21	
Pollution Degree per DIN VDE 0110, Table 1			2	
Maximum Working Insulation Voltage		V_{IORM}	560	V peak
Input-to-Output Test Voltage, Method B1	$V_{IORM} \times 1.875 = V_{PR}$, 100% production test, t_m = 1 sec, partial discharge < 5 pC	V_{PR}	1050	V peak
Input-to-Output Test Voltage, Method A	$V_{IORM} \times 1.6 = V_{PR}$, t_m = 60 sec, partial discharge < 5 pC	V_{PR}		
After Environmental Tests Subgroup 1			896	V peak
After Input and/or Safety Test Subgroup 2 and Subgroup 3	$V_{IORM} \times 1.2 = V_{PR}$, t_m = 60 sec, partial discharge < 5 pC		672	V peak
Highest Allowable Overvoltage	Transient overvoltage, t_{TR} = 10 seconds	V_{TR}	4000	V peak
Safety-Limiting Values	Maximum value allowed in the event of a failure (see Figure 3)			
Case Temperature		T_S	150	°C
Side 1 Current		I_{S1}	150	mA
Side 2 Current		I_{S2}	160	mA
Insulation Resistance at T_S	V_{IO} = 500 V	R_S	>10^9	Ω

Figure 3. Thermal Derating Curve, Dependence of Safety-Limiting Values on Case Temperature, per DIN V VDE V 0884-10

RECOMMENDED OPERATING CONDITIONS

Table 8.

Parameter	Symbol	Min	Max	Unit
Operating Temperature	T_A	−40	+105	°C
Supply Voltages[1]	V_{DD1}, V_{DD2}	2.7	5.5	V
Input Signal Rise and Fall Times			1.0	ms

[1] All voltages are relative to their respective ground. See the DC Correctness and Magnetic Field Immunity section for information on immunity to external magnetic fields.

ABSOLUTE MAXIMUM RATINGS

Ambient temperature = 25°C, unless otherwise noted.

Table 9.

Parameter	Min	Max	Unit
Storage Temperature (T_{ST})	−55	+150	°C
Ambient Operating Temperature (T_A)	−40	+105	°C
Supply Voltages (V_{DD1}, V_{DD2})[1]	−0.5	+7.0	V
Input Voltage (V_{IA}, V_{IB})[1, 2]	−0.5	V_{DDI} + 0.5	V
Output Voltage (V_{OA}, V_{OB})[1, 2]	−0.5	V_{DDO} + 0.5	V
Average Output Current, per Pin (I_O)[3]	−35	+35	mA
Common-Mode Transients (CM_L, CM_H)[4]	−100	+100	kV/μs

[1] All voltages are relative to their respective ground.
[2] V_{DDI} and V_{DDO} refer to the supply voltages on the input and output sides of a given channel, respectively.
[3] See Figure 3 for maximum rated current values for various temperatures.
[4] Refers to common-mode transients across the insulation barrier. Common-mode transients exceeding the Absolute Maximum Rating can cause latch-up or permanent damage.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

Table 10. Maximum Continuous Working Voltage[1]

Parameter	Max	Unit	Constraint
AC Voltage, Bipolar Waveform	565	V peak	50-year minimum lifetime
AC Voltage, Unipolar Waveform			
Functional Insulation	1131	V peak	Maximum approved working voltage per IEC 60950-1
Basic Insulation	560	V peak	Maximum approved working voltage per IEC 60950-1 and VDE V 0884-10
DC Voltage			
Functional Insulation	1131	V peak	Maximum approved working voltage per IEC 60950-1
Basic Insulation	560	V peak	Maximum approved working voltage per IEC 60950-1 and VDE V 0884-10

[1] Refers to continuos voltage magnitude imposed across the isolation barrier. See the Insulation Lifetime section for more details.

Table 11. ADuM3200 Truth Table (Positive Logic)

V_{IA} Input	V_{IB} Input	V_{DD1} State	V_{DD2} State	V_{OA} Output	V_{OB} Output	Notes
H	H	Powered	Powered	H	H	
L	L	Powered	Powered	L	L	
H	L	Powered	Powered	H	L	
L	H	Powered	Powered	L	H	
X	X	Unpowered	Powered	H	H	Outputs return to the input state within 1 μs of V_{DDI} power restoration.
X	X	Powered	Unpowered	Indeterminate	Indeterminate	Outputs return to the input state within 1 μs of V_{DDO} power restoration.

Table 12. ADuM3201 Truth Table (Positive Logic)

| V_{IA} Input	V_{IB} Input	V_{DD1} State	V_{DD2} State	V_{OA} Output	V_{OB} Output	Notes
H	H	Powered	Powered	H	H	
L	L	Powered	Powered	L	L	
H	L	Powered	Powered	H	L	
L	H	Powered	Powered	L	H	
X	X	Unpowered	Powered	Indeterminate	H	Outputs return to the input state within 1 μs of V_{DDI} power restoration.
X	X	Powered	Unpowered	H	Indeterminate	Outputs return to the input state within 1 μs of V_{DDO} power restoration.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS
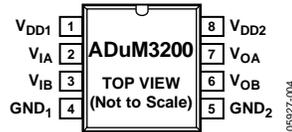
Figure 4. ADuM3200 Pin Configuration

Table 13. ADuM3200 Pin Function Descriptions

Pin No.	Mnemonic	Function
1	V_{DD1}	Supply Voltage for Isolator Side 1, 2.7 V to 5.5 V.
2	V_{IA}	Logic Input A.
3	V_{IB}	Logic Input B.
4	GND_1	Ground 1. Ground reference for Isolator Side 1.
5	GND_2	Ground 2. Ground reference for Isolator Side 2.
6	V_{OB}	Logic Output B.
7	V_{OA}	Logic Output A.
8	V_{DD2}	Supply Voltage for Isolator Side 2, 2.7 V to 5.5 V.
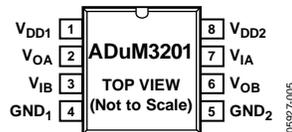
Figure 5. ADuM3201 Pin Configuration

Table 14. ADuM3201 Pin Function Descriptions

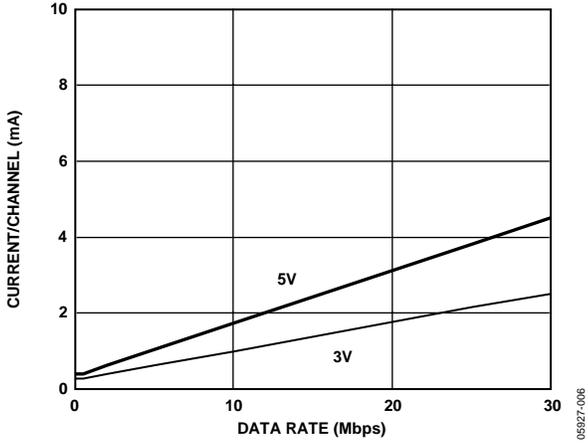| Pin No.	Mnemonic	Function
1	V_{DD1}	Supply Voltage for Isolator Side 1, 2.7 V to 5.5 V.
2	V_{OA}	Logic Output A.
3	V_{IB}	Logic Input B.
4	GND_1	Ground 1. Ground reference for Isolator Side 1.
5	GND_2	Ground 2. Ground reference for Isolator Side 2.
6	V_{OB}	Logic Output B.
7	V_{IA}	Logic Input A.
8	V_{DD2}	Supply Voltage for Isolator Side 2, 2.7 V to 5.5 V.

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 6. Typical Input Supply Current per Channel vs.
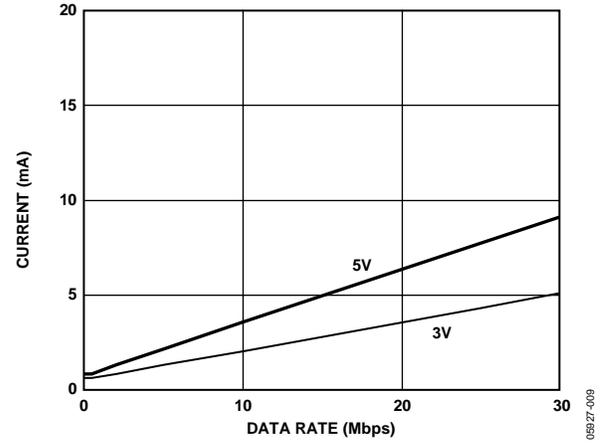Data Rate for 5 V and 3 V Operation

Figure 7. Typical Output Supply Current per Channel vs.
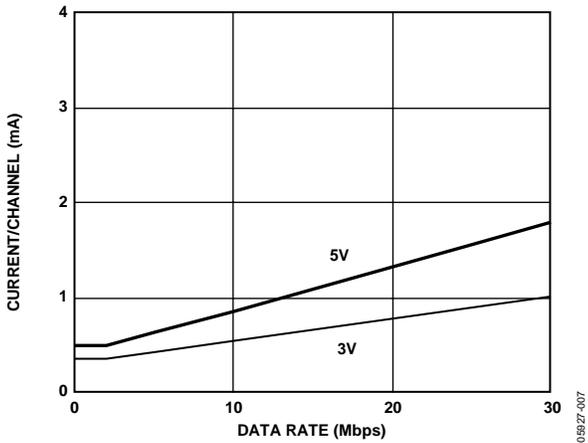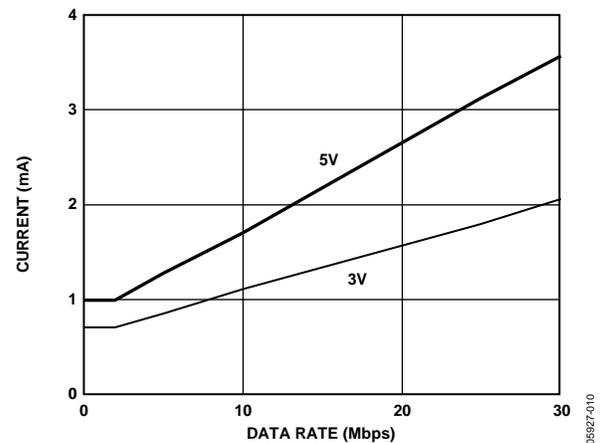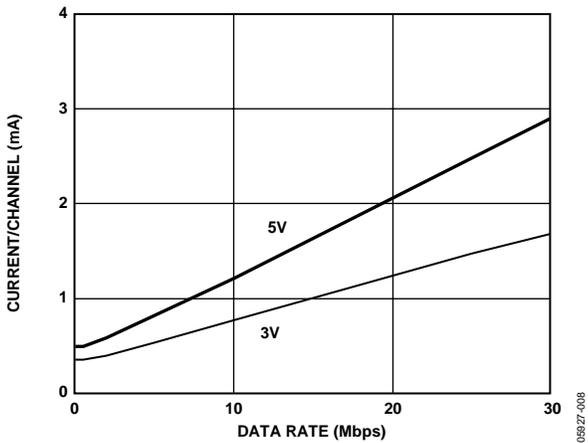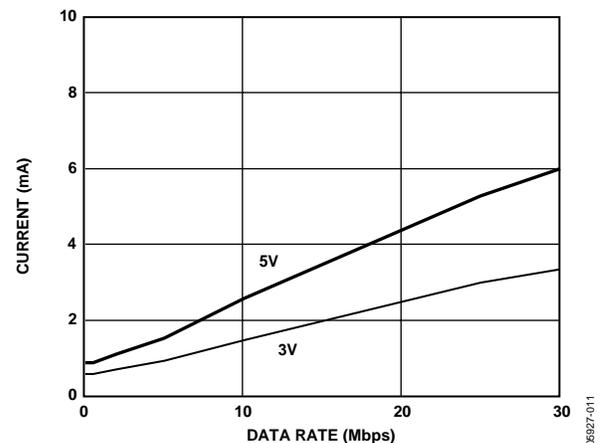Data Rate for 5 V and 3 V Operation (No Output Load)

Figure 8. Typical Output Supply Current per Channel vs.
Data Rate for 5 V and 3 V Operation (15 pF Output Load)

Figure 9. Typical ADuM3200 V_{DD1} Supply Current vs.
Data Rate for 5 V and 3 V Operation

Figure 10. Typical ADuM3200 V_{DD2} Supply Current vs.
Data Rate for 5 V and 3 V Operation

Figure 11. Typical ADuM3201 V_{DD1} or V_{DD2} Supply Current vs.
Data Rate for 5 V and 3 V Operation

APPLICATION INFORMATION

PC BOARD LAYOUT

The ADuM320x digital isolators require no external interface circuitry for the logic interfaces. Power supply bypassing is strongly recommended at the input and output supply pins. The capacitor value should be between 0.01 μF and 0.1 μF. The total lead length between both ends of the capacitor and the input power supply pin should not exceed 20 mm.

SYSTEM-LEVEL ESD CONSIDERATIONS AND ENHANCEMENTS

System-level ESD reliability (for example, per IEC 61000-4-x) is highly dependent on system design which varies widely by application. The ADuM320x incorporate many enhancements to make ESD reliability less dependent on system design. The enhancements include:

- ESD protection cells added to all input/output interfaces.

- Key metal trace resistances reduced using wider geometry and paralleling of lines with vias.

- The SCR effect inherent in CMOS devices minimized by use of guarding and isolation technique between PMOS and NMOS devices.

- Areas of high electric field concentration eliminated using 45° corners on metal traces.

- Supply pin overvoltage prevented with larger ESD clamps between each supply pin and its respective ground.

While the ADuM320x improve system-level ESD reliability, they are no substitute for a robust system-level design. See Application Note AN-793, ESD/Latch-Up Considerations with iCoupler Isolation Products for detailed recommendations on board layout and system-level design.

PROPAGATION DELAY-RELATED PARAMETERS

Propagation delay is a parameter that describes the time it takes a logic signal to propagate through a component. The propagation delay to a logic low output can differ from the propagation delay to a logic high.
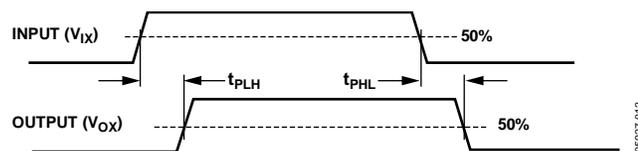

Figure 12. Propagation Delay Parameters

Pulse width distortion is the maximum difference between these two propagation delay values and is an indication of how accurately the input signal's timing is preserved.

Channel-to-channel matching refers to the maximum amount that the propagation delay differs between channels within a single ADuM320x component.

Propagation delay skew refers to the maximum amount that the propagation delay differs between multiple ADuM320x components operating under the same conditions.

DC CORRECTNESS AND MAGNETIC FIELD IMMUNITY

Positive and negative logic transitions at the isolator input cause narrow (~1 ns) pulses to be sent to the decoder via the transformer. The decoder is bistable and is therefore either set or reset by the pulses, indicating input logic transitions. In the absence of logic transitions of more than ~1 μs at the input, a periodic set of refresh pulses indicative of the correct input state are sent to ensure dc correctness at the output. If the decoder receives no internal pulses for more than about 5 μs, the input side is assumed to be unpowered or nonfunctional, in which case, the isolator output is forced to a default state (see Table 8) by the watchdog timer circuit.

The ADuM320x are extremely immune to external magnetic fields. The limitation on the ADuM320x's magnetic field immunity is set by the condition in which induced voltage in the transformer's receiving coil is sufficiently large to either falsely set or reset the decoder. The following analysis defines the conditions under which this can occur. The 3 V operating condition of the ADuM320x is examined because it represents the most susceptible mode of operation.

The pulses at the transformer output have an amplitude greater than 1.0 V. The decoder has a sensing threshold at about 0.5 V, therefore establishing a 0.5 V margin in which induced voltages can be tolerated. The voltage induced across the receiving coil is given by

$$V = (-d\beta/dt) \sum \pi r_n^2, n = 1, 2, \ldots, N$$

where:

β is the magnetic flux density (gauss).
N is the number of turns in the receiving coil.
r_n is the radius of the nth turn in the receiving coil (cm).

Given the geometry of the receiving coil in the ADuM320x and an imposed requirement that the induced voltage is at most 50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated, as shown in Figure 13.
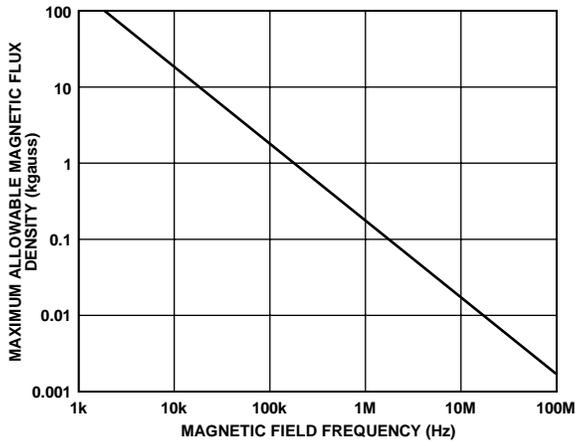
Figure 13. Maximum Allowable External Magnetic Flux Density

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.2 kgauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and does not cause a faulty output transition. Similarly, if such an event were to occur during a transmitted pulse (and had the worst-case polarity), it would reduce the received pulse from >1.0 V to 0.75 V—still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances away from the ADuM320x transformers. Figure 14 expresses these allowable current magnitudes as a function of frequency for selected distances. As seen, the ADuM320x are extremely immune and can be affected only by extremely large currents operated at high frequency and very close to the component. For the 1 MHz example, one would have to place a 0.5 kA current 5 mm away from the ADuM320x to affect the component's operation.
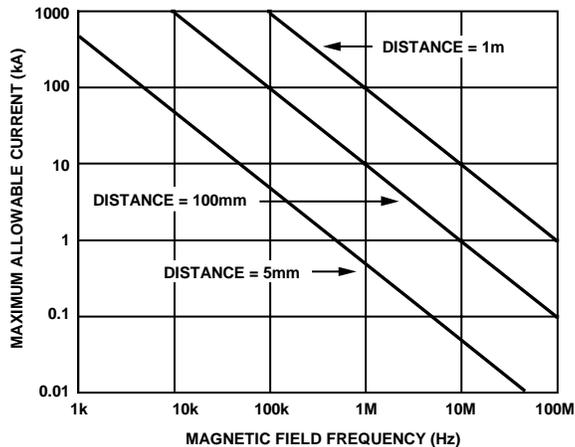

Figure 14. Maximum Allowable Current for Various Current-to-ADuM320x Spacing

Note that at combinations of strong magnetic fields and high frequencies, any loops formed by printed circuit board traces could induce sufficiently large error voltages to trigger the threshold of succeeding circuitry. Care should be taken in the layout of such traces to avoid this possibility.

POWER CONSUMPTION

The supply current at a given channel of the ADuM320x isolator is a function of the supply voltage, the channel's data rate, and the channel's output load.

For each input channel, the supply current is given by

$$I_{DDI} = I_{DDI(Q)} \qquad\qquad f \le 0.5 f_r$$

$$I_{DDI} = I_{DDI(D)} \times (2f - f_r) + I_{DDI(Q)} \qquad f > 0.5 f_r$$

for each output channel, the supply current is given by

$$I_{DDO} = I_{DDO(Q)} \qquad\qquad f \le 0.5 f_r$$

$$I_{DDO} = (I_{DDO(D)} + (0.5 \times 10^{-3}) \times C_L V_{DDO}) \times (2f - f_r) + I_{DDO(Q)}$$
$$f > 0.5 f_r$$

where:

$I_{DDI(D)}$, $I_{DDO(D)}$ are the input and output dynamic supply currents per channel (mA/Mbps).

C_L is the output load capacitance (pF).

V_{DDO} is the output supply voltage (V).

f is the input logic signal frequency (MHz, half of the input data rate, NRZ signaling).

f_r is the input stage refresh rate (Mbps).

$I_{DDI(Q)}$, $I_{DDO(Q)}$ are the specified input and output quiescent supply currents (mA).

To calculate the total I_{DD1} and I_{DD2} supply current, the supply currents for each input and output channel corresponding to I_{DD1} and I_{DD2} are calculated and totaled. Figure 6 provides per-channel input supply currents as a function of data rate.

Figure 7 and Figure 8 provide per-channel output supply currents as a function of data rate for an unloaded output condition and for a 15 pF output condition, respectively. Figure 9 through Figure 11 provide total V_{DD1} and V_{DD2} supply current as a function of data rate for ADuM3200 and ADuM3201 channel configurations.

INSULATION LIFETIME

All insulation structures eventually break down when subjected to voltage stress over a sufficiently long period. The rate of insulation degradation depends upon the characteristics of the voltage waveform applied across the insulation. In addition to the testing performed by the regulatory agencies, Analog Devices carries out an extensive set of evaluations to determine the lifetime of the insulation structure within the ADuM320x.

Analog Devices performs accelerated life testing using voltage levels higher than the rated continuous working voltage. Acceleration factors for several operating conditions are determined. These factors allow calculation of the time to failure at the actual working voltage.

The values shown in Table 10 summarize the peak voltage for 50 years of service life for a bipolar ac operating condition, and the maximum CSA/VDE approved working voltages. In many cases, the approved working voltage is higher than the 50-year service life voltage. Operation at these high working voltages can lead to shortened insulation life.

The insulation lifetime of the ADuM320x depends on the voltage waveform type imposed across the isolation barrier. The *i*Coupler insulation structure degrades at different rates depending on whether the waveform is bipolar ac, unipolar ac, or dc. Figure 15, Figure 16, and Figure 17 illustrate these different isolation voltage waveforms.

A bipolar ac voltage environment is the most stringent. The goal of a 50-year operating lifetime under the ac bipolar condition determines the ADI recommended maximum working voltage.

In the case of unipolar ac or dc voltage, the stress on the insulation is significantly lower. This allows operation at higher working voltages while still achieving a 50-year service life. The working voltages listed in Table 10 can be applied while maintaining the 50-year minimum lifetime, provided that the voltage conforms to either the unipolar ac or dc voltage cases. Any cross-insulation voltage waveform that does not conform to Figure 16 or Figure 17 should be treated as a bipolar ac waveform and its peak voltage should be limited to the 50-year lifetime voltage value listed in Table 10.

Note that the voltage presented in Figure 16 is shown as sinusoidal for illustration purposes only. It is meant to represent any voltage waveform varying between 0 V and some limiting value. The limiting value can be positive or negative, but the voltage cannot cross 0 V.
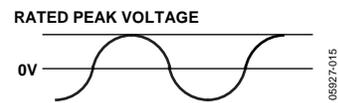

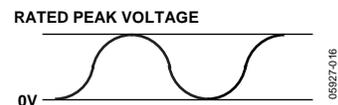*Figure 15. Bipolar AC Waveform*
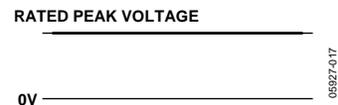

Figure 16. Unipolar AC Waveform

Figure 17. DC Waveform

OUTLINE DIMENSIONS

COMPLIANT TO JEDEC STANDARDS MS-012-A A
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 18. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body (R-8)
Dimensions shown in millimeters (inches)

ORDERING GUIDE

Model	Number of Inputs, V_{DD1} Side	Number of Inputs, V_{DD2} Side	Maximum Data Rate (Mbps)	Maximum Propagation Delay, 5 V (ns)	Maximum Pulse Width Distortion (ns)	Temperature Range (°C)	Package Option[1]
ADuM3200ARZ[2]	2	0	1	150	40	−40 to +105	R-8
ADuM3200ARZ-RL7[2]	2	0	1	150	40	−40 to +105	R-8
ADuM3200BRZ[2]	2	0	10	50	3	−40 to +105	R-8
ADuM3200BRZ-RL7[2]	2	0	10	50	3	−40 to +105	R-8
ADuM3200CRZ[2]	2	0	25	45	3	−40 to +105	R-8
ADuM3200CRZ-RL7[2]	2	0	25	45	3	−40 to +105	R-8
ADuM3201ARZ[2]	1	1	1	150	40	−40 to +105	R-8
ADuM3201ARZ-RL7[2]	1	1	1	150	40	−40 to +105	R-8
ADuM3201BRZ[2]	1	1	10	50	3	−40 to +105	R-8
ADuM3201BRZ-RL7[2]	1	1	10	50	3	−40 to +105	R-8
ADuM3201CRZ[2]	1	1	25	45	3	−40 to +105	R-8
ADuM3201CRZ-RL7[2]	1	1	25	45	3	−40 to +105	R-8

[1] R-8 = 8-lead narrow body SOIC_N.
[2] Z = RoHS Compliant Part.

NOTES

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**ANALOG
DEVICES**

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